

## TRIPLE 2-CHANNEL ANALOG MULTIPLEXER/DEMULTIPLEXER

## FEATURES

- Low "ON" resistance:  
80  $\Omega$  (typ.) at  $V_{CC} - V_{EE} = 4.5$  V  
70  $\Omega$  (typ.) at  $V_{CC} - V_{EE} = 6.0$  V  
60  $\Omega$  (typ.) at  $V_{CC} - V_{EE} = 9.0$  V
- Logic level translation:  
to enable 5 V logic to communicate with  $\pm 5$  V analog signals
- Typical "break before make" built in
- Output capability: non-standard
- $I_{CC}$  category: MSI

## GENERAL DESCRIPTION

The 74HC/HCT4053 are high-speed Si-gate CMOS devices and are pin compatible with the "4053" of the "4000B" series. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4053 are triple 2-channel analog multiplexers/demultiplexers with a common enable input ( $\bar{E}$ ). Each multiplexer/demultiplexer has two independent inputs/outputs ( $nY_0$  and  $nY_1$ ), a common input/output ( $nZ$ ) and three digital select inputs ( $S_1$  to  $S_3$ ).

With  $\bar{E}$  LOW, one of the two switches is selected (low impedance ON-state) by  $S_1$  to  $S_3$ . With  $\bar{E}$  HIGH, all switches are in the high impedance OFF-state, independent of  $S_1$  to  $S_3$ .

$V_{CC}$  and GND are the supply voltage pins for the digital control inputs ( $S_1$  to  $S_3$ , and  $\bar{E}$ ). The  $V_{CC}$  to GND ranges are 2.0 to 10.0 V for HC and 4.5 to 5.5 V for HCT. The analog inputs/outputs ( $nY_0$  and  $nY_1$ , and  $nZ$ ) can swing between  $V_{CC}$  as a positive limit and  $V_{EE}$  as a negative limit.  $V_{CC} - V_{EE}$  may not exceed 10.0 V.

For operation as a digital multiplexer/demultiplexer,  $V_{EE}$  is connected to GND (typically ground).

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
tpZH/ tpZL	turn "ON" time $\bar{E}$ to $V_{os}$ $S_n$ to $V_{os}$	$C_L = 15 \text{ pF}$ $R_L = 1 \text{ k}\Omega$ $V_{CC} = 5 \text{ V}$	17 21	23 21	ns ns
tPHZ/ tPLZ	turn "OFF" time $\bar{E}$ to $V_{os}$ $S_n$ to $V_{os}$		18 17	20 19	ns ns
$C_I$	input capacitance		3.5	3.5	pF
$C_{PD}$	power dissipation capacitance per switch	notes 1 and 2	36	36	pF
$C_S$	max. switch capacitance independent (Y) common (Z)		5 8	5 8	pF pF

$V_{EE} = \text{GND} = 0 \text{ V}$ ;  $T_{amb} = 25^\circ\text{C}$ ;  $t_f = t_r = 6 \text{ ns}$

## Notes

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \} \text{ where:}$$

$f_i$  = input frequency in MHz       $C_L$  = output load capacitance in pF  
 $f_o$  = output frequency in MHz       $C_S$  = max. switch capacitance in pF  
 $\sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \}$  = sum of outputs       $V_{CC}$  = supply voltage in V

2. For HC the condition is  $V_I = \text{GND}$  to  $V_{CC}$   
For HCT the condition is  $V_I = \text{GND}$  to  $V_{CC} - 1.5 \text{ V}$

## PACKAGE OUTLINES

16-lead DIL; plastic (SOT38Z).  
16-lead mini-pack; plastic (SO16; SOT109A).

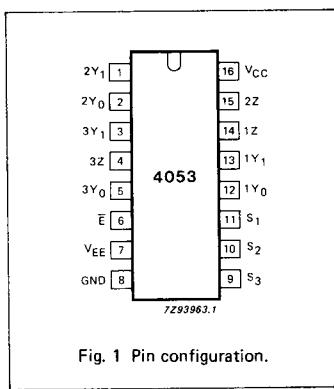


Fig. 1 Pin configuration.

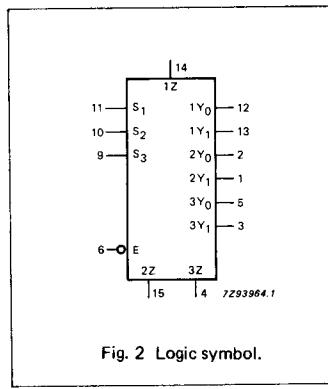


Fig. 2 Logic symbol.

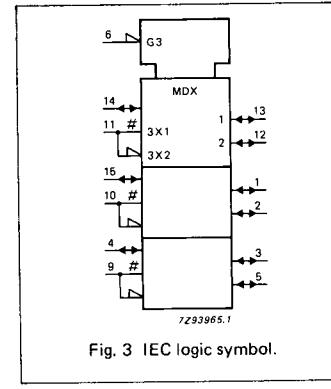


Fig. 3 IEC logic symbol.

**PIN DESCRIPTION**

PIN NO.	SYMBOL	NAME AND FUNCTION
2, 1	2Y <sub>0</sub> , 2Y <sub>1</sub>	independent inputs/outputs
5, 3	3Y <sub>0</sub> , 3Y <sub>1</sub>	independent inputs/outputs
6	E	enable input (active LOW)
7	V <sub>EE</sub>	negative supply voltage
8	GND	ground (0 V)
11, 10, 9	S <sub>1</sub> to S <sub>3</sub>	select inputs
12, 13	1Y <sub>0</sub> , 1Y <sub>1</sub>	independent inputs/outputs
14, 15, 4	1Z to 3Z	common inputs/outputs
16	V <sub>CC</sub>	positive supply voltage

**APPLICATIONS**

- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating

**FUNCTION TABLE**

INPUTS		CHANNEL ON
E	S <sub>n</sub>	
L	L	nY <sub>0</sub> - nZ
L	H	nY <sub>1</sub> - nZ
H	X	none

H = HIGH voltage level

L = LOW voltage level

X = don't care

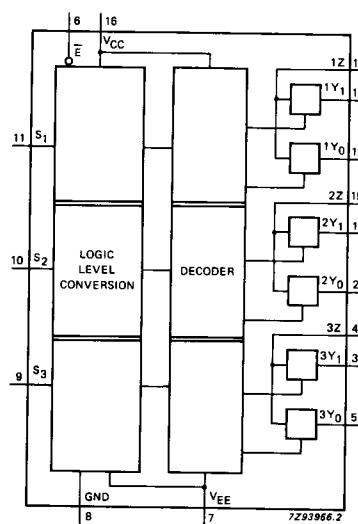


Fig. 4 Functional diagram.

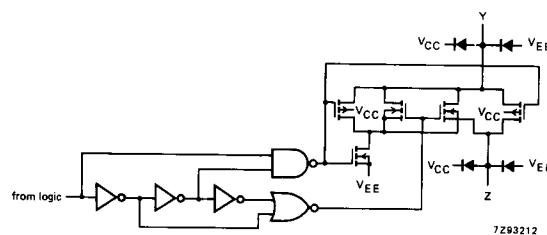


Fig. 5 Schematic diagram (one switch).

**RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Voltages are referenced to  $V_{EE}$  = GND (ground = 0 V)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	CONDITIONS
$V_{CC}$	DC supply voltage	-0.5	+11.0	V	
$\pm I_{IK}$	DC digital input diode current		20	mA	for $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V
$\pm I_{SK}$	DC switch diode current		20	mA	for $V_S < -0.5$ V or $V_S > V_{CC} + 0.5$ V
$\pm I_S$	DC switch current		25	mA	for $-0.5$ V < $V_S$ < $V_{CC} + 0.5$ V
$\pm I_{EE}$	DC $V_{EE}$ current		20	mA	
$\pm I_{CC}$ $\pm I_{GND}$	DC $V_{CC}$ or GND current		50	mA	
$T_{stg}$	storage temperature range	-65	+150	°C	
$P_{tot}$	power dissipation per package				for temperature range: -40 to +125 °C 74HC/HCT
	plastic DIL		750	mW	above +70 °C: derate linearly with 12 mW/K
	plastic mini-pack (SO)		500	mW	above +70 °C: derate linearly with 8 mW/K
$P_S$	power dissipation per switch		100	mW	

**Note to ratings**

To avoid drawing  $V_{CC}$  current out of terminals nZ, when switch current flows in terminals nY<sub>n</sub>, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminals nZ, no  $V_{CC}$  current will flow out of terminals nY<sub>n</sub>. In this case there is no limit for the voltage drop across the switch, but the voltages at nY<sub>n</sub> and nZ may not exceed  $V_{CC}$  or  $V_{EE}$ .

**RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	74HC			74HCT			UNIT	CONDITIONS
		min.	typ.	max.	min.	typ.	max.		
$V_{CC}$	DC supply voltage $V_{CC}$ -GND	2.0	5.0	10.0	4.5	5.0	5.5	V	see Figs 6 and 7
$V_{CC}$	DC supply voltage $V_{CC}$ - $V_{EE}$	2.0	5.0	10.0	2.0	5.0	10.0	V	see Figs 6 and 7
$V_I$	DC input voltage range	GND		$V_{CC}$	GND		$V_{CC}$	V	
$V_S$	DC switch voltage range	$V_{EE}$		$V_{CC}$	$V_{EE}$		$V_{CC}$	V	
$T_{amb}$	operating ambient temperature range	-40		+85	-40		+85	°C	see DC and AC CHARACTERISTICS
$T_{amb}$	operating ambient temperature range	-40		+125	-40		+125	°C	
$t_r, t_f$	input rise and fall times		6.0	1000 500 400 250		6.0	500	ns	$V_{CC} = 2.0$ V $V_{CC} = 4.5$ V $V_{CC} = 6.0$ V $V_{CC} = 10.0$ V

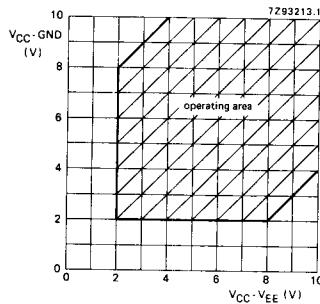


Fig. 6 Guaranteed operating area as a function of the supply voltages for 74HC4053.

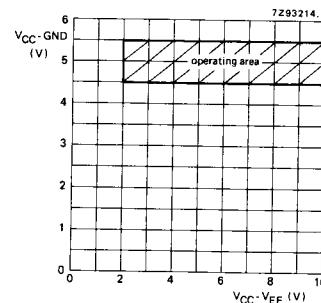


Fig. 7 Guaranteed operating area as a function of the supply voltages for 74HCT4053.

**DC CHARACTERISTICS FOR 74HC/HCT**For 74HC:  $V_{CC} - GND$  or  $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$  and  $9.0\text{ V}$ For 74HCT:  $V_{CC} - GND = 4.5$  and  $5.5\text{ V}$ ;  $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$  and  $9.0\text{ V}$ 

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS										
		74HC/HCT							V <sub>CC</sub> V	V <sub>EE</sub> V	I <sub>S</sub> μA	V <sub>is</sub>	V <sub>I</sub>						
		+25		-40 to +85		-40 to +125													
		min.	typ.	max.	min.	max.	min.												
R <sub>ON</sub>	ON resistance (peak)	—	—	—	—	—	—	Ω	2.0	0	100	V <sub>CC</sub> to V <sub>EE</sub>	V <sub>IH</sub> or V <sub>IL</sub>						
		100	180	225	270	240	195	Ω	4.5	0	1000								
		90	160	200	240	220	175	Ω	6.0	0	1000								
		70	130	165	195	175	130	Ω	4.5	-4.5	1000								
R <sub>ON</sub>	ON resistance (rail)	150	—	—	—	—	—	Ω	2.0	0	100	V <sub>EE</sub>	V <sub>IH</sub> or V <sub>IL</sub>						
		80	140	175	210	180	150	Ω	4.5	0	1000								
		70	120	150	180	160	130	Ω	6.0	0	1000								
		60	105	130	160	140	105	Ω	4.5	-4.5	1000								
R <sub>ON</sub>	ON resistance (rail)	150	—	—	—	—	—	Ω	2.0	0	100	V <sub>CC</sub>	V <sub>IH</sub> or V <sub>IL</sub>						
		90	160	200	240	210	175	Ω	4.5	0	1000								
		80	140	175	210	180	150	Ω	6.0	0	1000								
		65	120	150	180	160	120	Ω	4.5	-4.5	1000								
ΔR <sub>ON</sub>	maximum ΔR <sub>ON</sub> resistance between any two channels	—	—	—	—	—	—	Ω	2.0	0	—	V <sub>CC</sub> to V <sub>EE</sub>	V <sub>IH</sub> or V <sub>IL</sub>						
		9	—	—	—	—	—	Ω	4.5	0	—								
		8	—	—	—	—	—	Ω	6.0	0	—								
		6	—	—	—	—	—	Ω	4.5	-4.5	—								

**Notes to DC characteristics**

- At supply voltages ( $V_{CC} - V_{EE}$ ) approaching 2.0 V the analog switch ON-resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
- For test circuit measuring R<sub>ON</sub> see Fig. 8.

## DC CHARACTERISTICS FOR 74HC

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS								
		74HC							V <sub>CC</sub> V	V <sub>EE</sub> V	V <sub>I</sub>	OTHER					
		+25		-40 to +85		-40 to +125											
		min.	typ.	max.	min.	max.	min.										
V <sub>IH</sub>	HIGH level input voltage	1.5 3.15 4.2 6.3	1.2 2.4 3.2 4.7		1.5 3.15 4.2 6.3		1.5 3.15 4.2 6.3		V	2.0 4.5 6.0 9.0							
V <sub>IL</sub>	LOW level input voltage		0.8 2.1 2.8 4.3	0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7	V	2.0 4.5 6.0 9.0							
±I <sub>I</sub>	input leakage current			0.1 0.2		1.0 2.0		1.0 2.0	μA	6.0 10.0	0 0	V <sub>CC</sub> or GND					
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>					
±I <sub>S</sub>	analog switch OFF-state current all channels			0.1		1.0		1.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>					
±I <sub>S</sub>	analog switch ON-state current			0.1		1.0		1.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>					
I <sub>CC</sub>	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	6.0 10.0	0 0	V <sub>CC</sub> or GND					
												V <sub>is</sub> = V <sub>EE</sub> or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or V <sub>EE</sub>					

## AC CHARACTERISTICS FOR 74HC

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)							UNIT	TEST CONDITIONS						
		74HC								V <sub>CC</sub> V	V <sub>EE</sub> V	OTHER				
		+25			-40 to +85		-40 to +125									
		min.	typ.	max.	min.	max.	min.	max.								
t <sub>PHL</sub> / t <sub>PLH</sub>	propagation delay V <sub>is</sub> to V <sub>os</sub>		15 5 4 4	60 12 10 8		75 15 13 10		90 18 15 12	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig. 18)				
t <sub>PZH</sub> / t <sub>PZL</sub>	turn "ON" time E to V <sub>os</sub>		60 20 16 15	220 44 37 31		275 55 47 39		330 66 56 47	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19, 20 and 21)				
t <sub>PZH</sub> / t <sub>PZL</sub>	turn "ON" time S <sub>n</sub> to V <sub>os</sub>		75 25 20 15	220 44 37 31		275 55 47 39		330 66 56 47	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19, 20 and 21)				
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn "OFF" time E to V <sub>os</sub>		63 21 17 15	210 42 36 29		265 53 45 36		315 63 54 44	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19, 20 and 21)				
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn "OFF" time S <sub>n</sub> to V <sub>os</sub>		60 20 16 15	210 42 36 29		265 53 45 36		315 63 54 44	ns	2.0 4.5 6.0 4.5	0 0 0 -4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 19, 20 and 21)				

## DC CHARACTERISTICS FOR 74HCT

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS							
		74HCT							V <sub>CC</sub> V	V <sub>EE</sub> V	V <sub>I</sub>	OTHER				
		+25			−40 to +85		−40 to +125									
		min.	typ.	max.	min.	max.	min.	max.								
V <sub>IH</sub>	HIGH level input voltage	2.0	1.6		2.0		2.0		V	4.5 to 5.5						
V <sub>IL</sub>	LOW level input voltage		1.2	0.8		0.8		0.8	V	4.5 to 5.5						
±I <sub>I</sub>	input leakage current			0.1		1.0		1.0	μA	5.5	0	V <sub>CC</sub> or GND				
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>				
±I <sub>S</sub>	analog switch OFF-state current all channels			0.1		1.0		1.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>				
±I <sub>S</sub>	analog switch ON-state current			0.1		1.0		1.0	μA	10.0	0	V <sub>IH</sub> or V <sub>IL</sub>				
I <sub>CC</sub>	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	5.5 5.0	0 −5.0	V <sub>CC</sub> or GND				
ΔI <sub>CC</sub>	additional quiescent supply current per input pin for unit load coefficient is 1 (note 1)		100	360		450		490	μA	4.5 to 5.5	0	V <sub>CC</sub> −2.1 V				

## Note to HCT types

1. The value of additional quiescent supply current ( $\Delta I_{CC}$ ) for a unit load of 1 is given here.To determine  $\Delta I_{CC}$  per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
S <sub>n</sub> E	0.50 0.50

## AC CHARACTERISTICS FOR 74HCT

GND = 0 V;  $t_r = t_f = 6 \text{ ns}$ ;  $C_L = 50 \text{ pF}$ 

SYMBOL	PARAMETER	$T_{\text{amb}}$ ( $^{\circ}\text{C}$ )						UNIT	TEST CONDITIONS					
		74HCT							V <sub>CC</sub> V	V <sub>EE</sub> V	OTHER			
		+25			−40 to +85		−40 to +125							
		min.	typ.	max.	min.	max.	min.	max.						
$t_{\text{PHL}}/t_{\text{PLH}}$	propagation delay $V_{\text{IS}}$ to $V_{\text{OS}}$		5 4	12 8		15 10		18 12	ns	4.5 4.5	0 −4.5	$R_L = \infty$ ; $C_L = 50 \text{ pF}$ (see Fig. 18)		
$t_{\text{PZH}}/t_{\text{PZL}}$	turn "ON" time $\bar{E}$ to $V_{\text{OS}}$		27 16	48 34		60 43		72 51	ns	4.5 4.5	0 −4.5	$R_L = 1 \text{ k}\Omega$ ; $C_L = 50 \text{ pF}$ (see Figs 19, 20 and 21)		
$t_{\text{PZH}}/t_{\text{PZL}}$	turn "ON" time $S_n$ to $V_{\text{OS}}$		25 16	48 34		60 43		72 51	ns	4.5 4.5	0 −4.5	$R_L = 1 \text{ k}\Omega$ ; $C_L = 50 \text{ pF}$ (see Figs 19, 20 and 21)		
$t_{\text{PHZ}}/t_{\text{PLZ}}$	turn "OFF" time $\bar{E}$ to $V_{\text{OS}}$		24 15	44 31		55 39		66 47	ns	4.5 4.5	0 −4.5	$R_L = 1 \text{ k}\Omega$ ; $C_L = 50 \text{ pF}$ (see Figs 19, 20 and 21)		
$t_{\text{PHZ}}/t_{\text{PLZ}}$	turn "OFF" time $S_n$ to $V_{\text{OS}}$		22 15	44 31		55 39		66 47	ns	4.5 4.5	0 −4.5	$R_L = 1 \text{ k}\Omega$ ; $C_L = 50 \text{ pF}$ (see Figs 19, 20 and 21)		

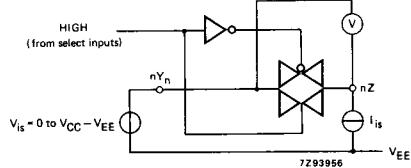
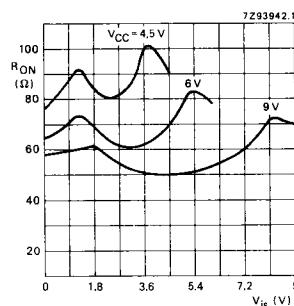
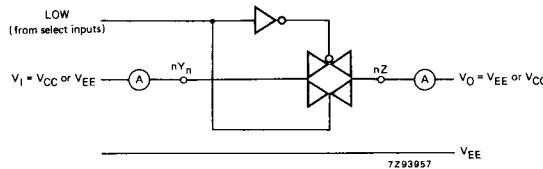
Fig. 8 Test circuit for measuring  $R_{ON}$ .Fig. 9 Typical  $R_{ON}$  as a function of input voltage  $V_{IS}$  for  $V_{IS} = 0$  to  $V_{CC} - V_{EE}$ .

Fig. 10 Test circuit for measuring OFF-state current.

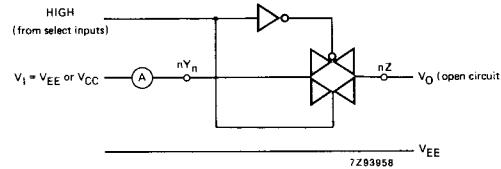


Fig. 11 Test circuit for measuring ON-state current.

## ADDITIONAL AC CHARACTERISTICS FOR 74HC/HCT

Recommended conditions and typical values

GND = 0 V;  $T_{amb}$  = 25 °C

SYMBOL	PARAMETER	typ.	UNIT	V <sub>CC</sub> V	V <sub>EE</sub> V	V <sub>is(p-p)</sub> V	CONDITIONS
	sine-wave distortion $f = 1$ kHz	0.04 0.02	% %	2.25 4.5	-2.25 -4.5	4.0 8.0	$R_L = 10$ kΩ; $C_L = 50$ pF (see Fig. 14)
	sine-wave distortion $f = 10$ kHz	0.12 0.06	% %	2.25 4.5	-2.25 -4.5	4.0 8.0	$R_L = 10$ kΩ; $C_L = 50$ pF (see Fig. 14)
	switch "OFF" signal feed-through	-50 -50	dB dB	2.25 4.5	-2.25 -4.5	note 1	$R_L = 600$ Ω; $C_L = 50$ pF $f = 1$ MHz (see Figs 12 and 15)
	crosstalk between any two switches/ multiplexers	-60 -60	dB dB	2.25 4.5	-2.25 -4.5	note 1	$R_L = 600$ Ω; $C_L = 50$ pF; $f = 1$ MHz (see Fig. 16)
V <sub>(p-p)</sub>	crosstalk voltage between control and any switch (peak-to-peak value)	110 220	mV mV	4.5 4.5	0 -4.5		$R_L = 600$ Ω; $C_L = 50$ pF; $f = 1$ MHz ( $E$ or $S_n$ , square-wave between $V_{CC}$ and GND, $t_r = t_f = 6$ ns) (see Fig. 17)
f <sub>max</sub>	minimum frequency response (-3dB)	160 170	MHz MHz	2.25 4.5	-2.25 -4.5	note 2	$R_L = 50$ Ω; $C_L = 10$ pF (see Figs 13 and 14)
C <sub>S</sub>	maximum switch capacitance independent (Y) common (Z)	5 8	pF pF				

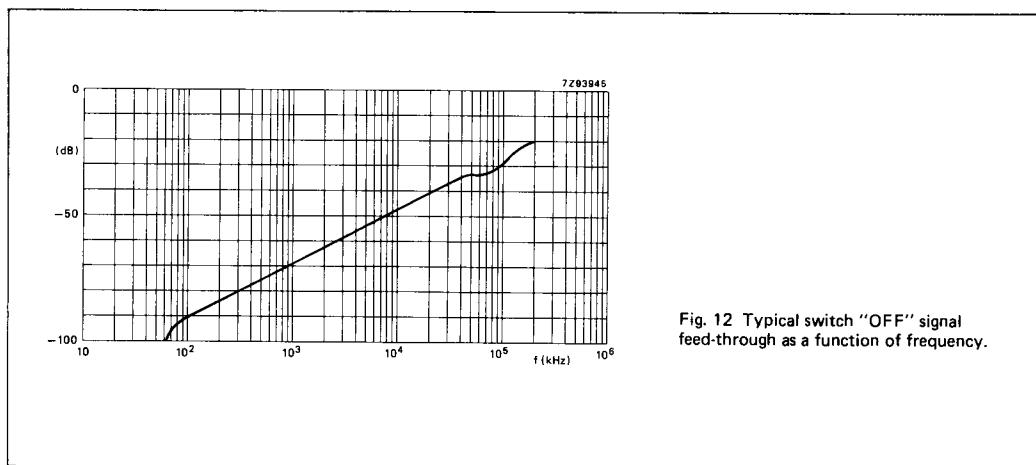
## Notes to AC characteristics

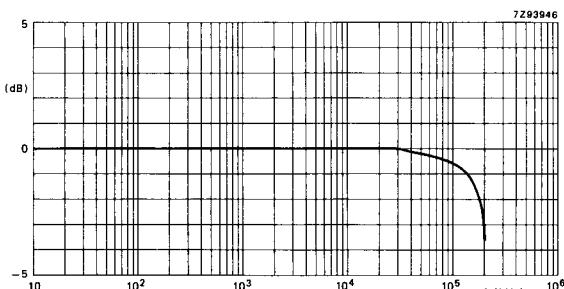
## General note

V<sub>is</sub> is the input voltage at an nY<sub>n</sub> or nZ terminal, whichever is assigned as an input.V<sub>os</sub> is the output voltage at an nY<sub>n</sub> or nZ terminal, whichever is assigned as an output.

## Notes

1. Adjust input voltage V<sub>is</sub> to 0 dBm level (0 dBm = 1 mW into 600 Ω).
2. Adjust input voltage V<sub>is</sub> to 0 dBm level at V<sub>os</sub> for 1 MHz (0 dBm = 1 mW into 50 Ω).





Note to Figs 12 and 13

Test conditions:  
 $V_{CC} = 4.5 \text{ V}$ ; GND = 0 V;  $V_{EE} = -4.5 \text{ V}$ ;  
 $R_L = 50 \Omega$ ;  $R_{source} = 1 \text{ k}\Omega$ .

Fig. 13 Typical frequency response.

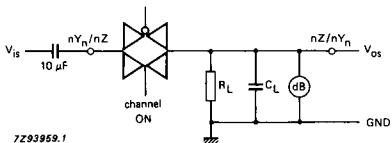


Fig. 14 Test circuit for measuring sine-wave distortion and minimum frequency response.

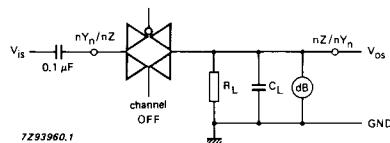
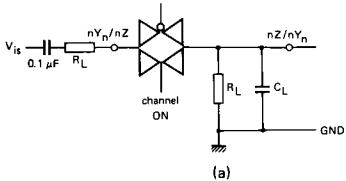
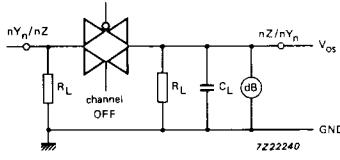


Fig. 15 Test circuit for measuring switch "OFF" signal feed-through.

Fig. 16 Test circuits for measuring crosstalk between any two switches/multiplexers.  
 (a) channel ON condition; (b) channel OFF condition.

(b)

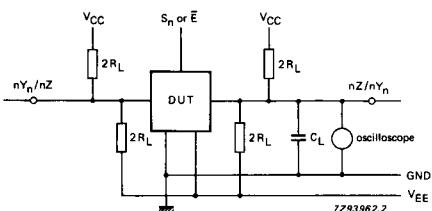
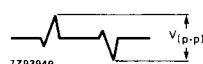


Fig. 17 Test circuit for measuring crosstalk between control and any switch.

Note to Fig. 17

The crosstalk is defined as follows  
 (oscilloscope output):



## AC WAVEFORMS

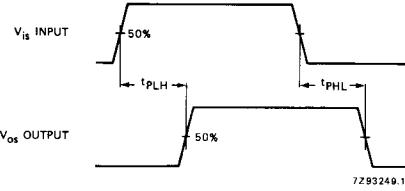


Fig. 18 Waveforms showing the input ( $V_{is}$ ) to output ( $V_{os}$ ) propagation delays.

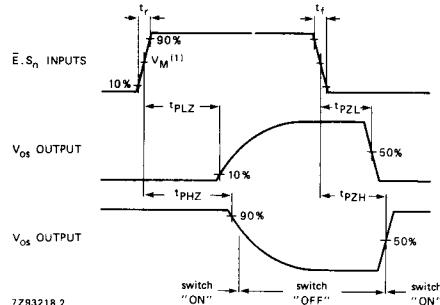


Fig. 19 Waveforms showing the turn-ON and turn-OFF times.

**Note to Fig. 19**

(1) HC :  $V_M = 50\%$ ;  $V_I = \text{GND to } V_{CC}$ .  
 HCT:  $V_M = 1.3 \text{ V}$ ;  $V_I = \text{GND to } 3 \text{ V}$ .

## TEST CIRCUIT AND WAVEFORMS

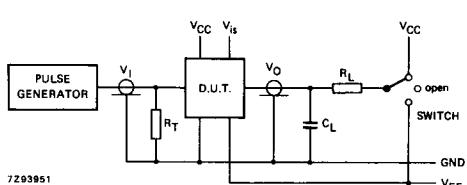


Fig. 20 Test circuit for measuring AC performance.

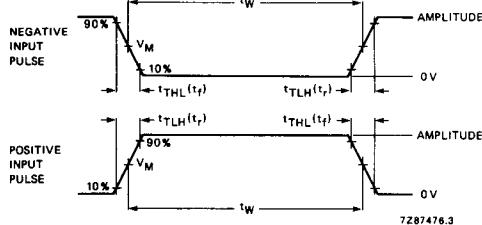


Fig. 21 Input pulse definitions.

## Conditions

TEST	SWITCH	$V_{IS}$
$t_{PZH}$	$V_{EE}$	$V_{CC}$
$t_{PZL}$	$V_{CC}$	$V_{EE}$
$t_{PHZ}$	$V_{EE}$	$V_{CC}$
$t_{PLZ}$	$V_{CC}$	$V_{EE}$
others	open	pulse

FAMILY	AMPLITUDE	$V_M$	$t_r; t_f$	
			$f_{max};$ PULSE WIDTH	OTHER
74HC 74HCT	$V_{CC}$ 3.0 V	50% 1.3 V	$< 2 \text{ ns}$ $< 2 \text{ ns}$	6 ns 6 ns

## Definitions for Figs 20 and 21:

$C_L$  = load capacitance including jig and probe capacitance  
(see AC CHARACTERISTICS for values).

$R_T$  = termination resistance should be equal to the output impedance  $Z_O$  of the pulse generator.

$t_r = t_f = 6 \text{ ns}$ ; when measuring  $f_{max}$ , there is no constraint on  $t_r, t_f$  with 50% duty factor.